Thyristor Semiconductor Device - Page 1 of 1



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### Inclosure Material:

Metal

**Overall Length:** 

0.625 inches

- Mounting Facility Quantity:
- 1

### Internal Configuration:

Junction contact

#### **Mounting Method:**

Threaded stud

#### **Features Provided:**

Hermetically sealed case

#### **Overall Width Across Flats:**

Between 0.551 inches and 0.559 inches

#### **Thread Size:**

0.250 inches

### Semiconductor Material:

Silicon

### Voltage Rating In Volts Per Characteristic:

200.0 repetitive peak reverse voltage and 250.0 nonrepetitive peak reverse voltage

### **Current Rating Per Characteristic:**

13.00 amperes forward current, total rms universal

## Power Rating Per Characteristic:

5.0 watts small-signal input power, common-collector blank

### Maximum Operating Tempurature Per Measurement Point:

100.0 degrees celsius junction

#### **Special Features:**

Junction pattern arrangement: pnpn

#### **Thread Series Designator:**

Unf

# Terminal Type And Quantity:

3 tab, solder lug

# **Specification Data:**

80131-release6291 professional/industrial association specification

### Shelf Life:

N/a

# Unit Of Measure:

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#### Demilitarization:

No

### Fiig:

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